

RAYCONN ELECTRONICS CO., LTD.

SPECIFICATION FORM

FEATURES

- ✧ 0.56 INCHES (14.20MM) DIGIT HEIGHT
- ✧ 25.00MM×19.0MM OUTLINE
- ✧ DUAL DIGIT
- ✧ SINGLE COLOR
- ✧ EASY ASSEMBLY
- ✧ HIGH BRIGHTNESS
- ✧ SOLID STATE RELIABILITY

DESCRIPTION

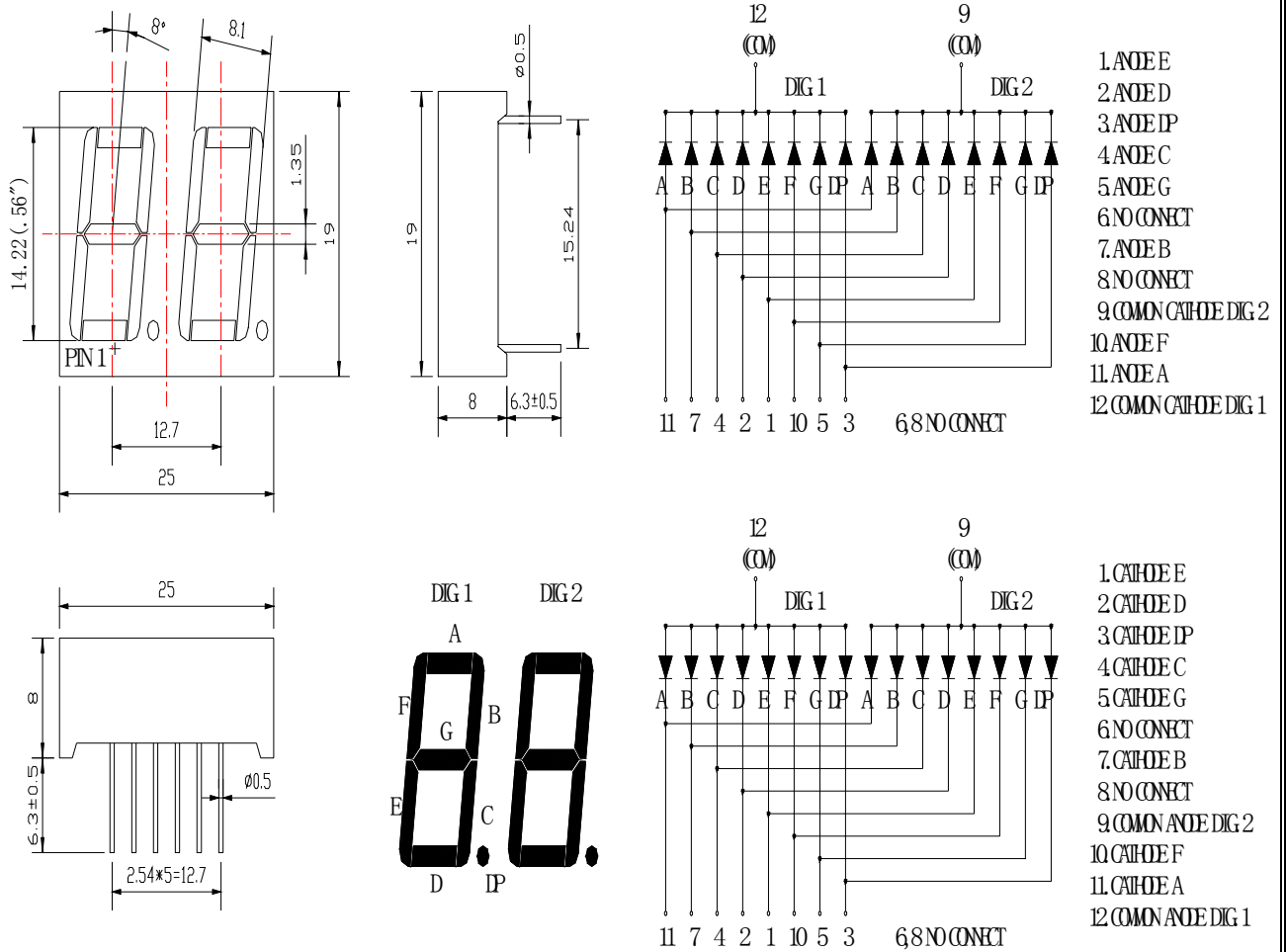
The REC-S5261AG/CG-3 is a 0.56 inches (14.20mm) digit height, 12.6mm×19.0mm outline, single color, dual digit numeric display. This display utilizes green LED chips fabricated from GaP epiwafer on GaP substrate grown by liquid phase epitaxy. These devices have black face and white segments.

DEVICE

PART NO.	EMITTING COLOR	DESCRIPTION
REC-S5261AG/CG-3	Yellow-Green	black Face with White Segments

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PACKAGE DIMENSION



ABSOLUTE MAXIMUM RATING AT $T_A=25^\circ\text{C}$

PARAMETER	SYMBOL	MAXIMUM	UNIT
Power Dissipation per Seg.	P_{AD}	75	mW
Peak Forward Current per Seg.	I_{PF}	80	mA
Continuous Forward Current per Seg.	I_{AF}	20	mA
Reverse Voltage per Seg.	V_R	5	V
Operating Temperature Range, T_{opr}		- 25° C to + 60° C	
Storage Temperature Range, T_{stg}		- 30° C to + 85° C	
Solder Temperature : 1 / 16 inch below seating plane for 3 seconds at 260° C			

Part No. : REC-S5261AG/CG-3

Reference No. : SP030117

Date : 05-1-24

Page : 2 of 3

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ELECTRO - OPTICAL CHARACTERISTICS AT $T_A=25^\circ\text{C}$

PARAMETER	UNIT	MIN	TYPE	MAX
Luminous Intensity per Seg., I_V ($I_F=20\text{mA}$)	mcd	10	13	17
Peak Emission Wavelength, λ_p ($I_F=20\text{mA}$)	nm		570	
Special Line Half-Width, $\Delta\lambda$ ($I_F=20\text{mA}$)	nm		30	
Forward Voltage per Seg., V_F ($I_F=20\text{mA}$)	V	2.0	2.15	2.20
Reverse Current per chipSeg., I_R , ($V_R=5\text{V}$)	μA			100
Luminous Intensity Matching Ratio, I_{V-m} ($I_F=20\text{mA}$)				2 : 1